

# 2Gb (x16 x 1 channel) Mobile LPDDR4/LPDDR4X

FEBRUARY 2022

## FEATURES

- Configuration:
  - 128Mb x16 x 1 channel
  - 8 internal banks
- Low-voltage Core and I/O Power Supplies
  - VDD1 = 1.70-1.95V
  - VDD2 = 1.06-1.17V
  - VDDQ = 1.06-1.17V (LPDDR4)
  - VDDQ = 0.57-0.65V (LPDDR4X)
- LVSTL(Low Voltage Swing Terminated Logic) I/O Interface
- Internal VREF and VREF Training
- Dynamic ODT :
  - DQ ODT :VSSQ Termination
  - CA ODT :VSS Termination
- Max. Clock Frequency : 1.6GHz (3.2Gbps)
- 16n Pre-fetch DDR architecture
- Single data rate (multiple cycles) command/ address bus
- Bidirectional/differential data strobe per byte of data (DQS/DQS#)
- Programmable burst lengths (16 or 32)
- ZQ Calibration
- Operation Temperature
  - Industrial (T<sub>c</sub> = -40°C to 95°C)
  - Automotive, A1 (T<sub>c</sub> = -40°C to 95°C)
  - Automotive, A2 (T<sub>c</sub> = -40°C to 105°C)
  - Automotive, A3 (T<sub>c</sub> = -40°C to 125°C)
- Clock-Stop capability

## DESCRIPTION

The IS43/46LQ16128A and IS43/46LQ1612AL are 2Gbit CMOS LPDDR4 SDRAM. The device is organized as 1 channel per device, and individual channel is 8-banks and 16-bits. This product uses a double-data-rate architecture to achieve high-speed operation. The double data rate architecture is essentially a 16N prefetch architecture with an interface designed to transfer two data words per clock cycle at the I/O pins. This product offers fully synchronous operations referenced to both rising and falling edges of the clock. The data paths are internally pipelined and 16n bits prefetched to achieve very high bandwidth.

- On-chip temperature sensor whose status can be read from MR4
- 200-ball x16 BGA (10x14.5 mm)

## ADDRESS TABLE

Parameter	
# of Channel	1
Row Addresses	R0-R13
Column Addresses	C0-C9
Bank Addresses	BA0-BA2

**Note:** Address information is per channel.

## KEY TIMING PARAMETERS

Speed Grade	Freq. (MHz)	Data Rate (Mb/s)	Write Latency		Read Latency	
			Set A	Set B	DBI OFF	DBI ON
-062	1600	3200	14	26	28	32
-075	1333	2666	12	22	24	28

**Note:** Other clock frequencies/data rates supported; please refer to AC timing tables.

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**1. BALL ASSIGNMENTS AND DESCRIPTIONS (for x16)**

200-ball x16 Discrete Package, 0.80mm x 0.65mm using MO-311

	1	2	3	4	5	6	7	8	9	10	11	12
0.80mm Pitch	A	DNU	DNU	VSS	VDD2	ZQ0		NC	VDD2	VSS	DNU	DNU
	B	DNU	DQ0_A	VDDQ	DQ7_A	VDDQ		VDDQ	DQ15_A	VDDQ	DQ8_A	DNU
	C	VSS	DQ1_A	DMI0_A	DQ6_A	VSS		VSS	DQ14_A	DMI1_A	DQ9_A	VSS
	D	VDDQ	VSS	DQS0_T_A	VSS	VDDQ		VDDQ	VSS	DQS1_T_A	VSS	VDDQ
	E	VSS	DQ2_A	DQS0_C_A	DQ5_A	VSS		VSS	DQ13_A	DQS1_C_A	DQ10_A	VSS
	F	VDD1	DQ3_A	VDDQ	DQ4_A	VDD2		VDD2	DQ12_A	VDDQ	DQ11_A	VDD1
	G	VSS	ODT_CA_A	VSS	VDD1	VSS		VSS	VDD1	VSS	NC	VSS
	H	VDD2	CA0_A	NC	CS0_A	VDD2		VDD2	CA2_A	CA3_A	CA4_A	VDD2
	J	VSS	CA1_A	VSS	CKE0_A	NC		CK_t_A	CK_c_A	VSS	CA5_A	VSS
	K	VDD2	VSS	VDD2	VSS	NC		NC	VSS	VDD2	VSS	VDD2
0.65mm Pitch	L											
	M											
	N	VDD2	VSS	VDD2	VSS	NC		NC	VSS	VDD2	VSS	VDD2
	P	VSS	NC	VSS	NC	NC		NC	NC	VSS	NC	VSS
	R	VDD2	NC	NC	NC	VDD2		VDD2	NC	NC	NC	VDD2
	T	VSS	NC	VSS	VDD1	VSS		VSS	VDD1	VSS	RESET_N	VSS
	U	VDD1	NC	VDDQ	NC	VDD2		VDD2	NC	VDDQ	NC	VDD1
	V	VSS	NC	NC	NC	VSS		VSS	NC	NC	NC	VSS
	W	VDDQ	VSS	NC	VSS	VDDQ		VDDQ	VSS	NC	VSS	VDDQ
	Y	VSS	NC	NC	NC	VSS		VSS	NC	NC	NC	VSS
	AA	DNU	NC	VDDQ	NC	VDDQ		VDDQ	NC	VDDQ	NC	DNU
	AB	DNU	DNU	VSS	VDD2	VSS		VSS	VDD2	VSS	DNU	DNU

NOTE 1 0.8mm pitch (X-axis), 0.65mm pitch (Y-axis), 22 rows.

NOTE 2 Top View, A1 in top left corner.

NOTE 3 Die pad VSS and VSSQ signals are combined to VSS package balls.

## 2. INPUT/OUTPUT FUNCTIONAL DESCRIPTION

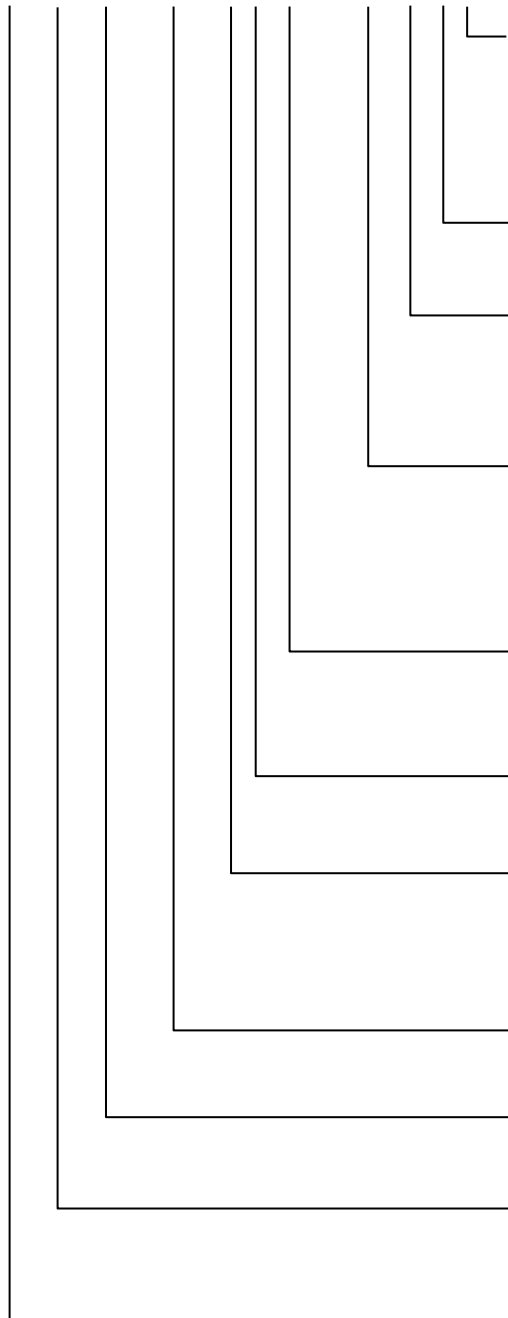
### 2.1 PAD DEFINITION AND DESCRIPTION

Table 2.1 — Pad Definition and Description

Symbol	Type	Description
CK_t_A, CK_c_A,	Input	<b>Clock:</b> CK_t and CK_c are differential clock inputs. All address, command, and control input signals are sampled on the crossing of the positive edge of CK_t and the negative edge of CK_c. AC timings for CA parameters are referenced to CK.
CKE_A	Input	<b>Clock Enable:</b> CKE HIGH activates and CKE LOW deactivates the internal clock circuits, input buffers, and output drivers. Power-saving modes are entered and exited via CKE transitions. CKE is part of the command code.
CS_A	Input	<b>Chip Select:</b> CS is part of the command code.
CA[5:0]_A	Input	<b>Command/Address Inputs:</b> CA signals provide the Command and Address inputs according to Table 63 — Command Truth Table.
ODT_CA_A	Input	<b>LPDDR4 CA ODT Control:</b> The ODT_CA pin is used in conjunction with the Mode Register to turn on/off the On-Die-Termination for CA pins. <b>LPDDR4X CA ODT Control:</b> The ODT_CA pin is ignored by LPDDR4X devices. CA ODT is fully controlled through MR11 and MR22. The ODT_CA pin shall be connected to either VDD2 or VSS.
DQ[15:0]_A,	I/O	<b>Data Input/Output:</b> Bi-direction data bus.
DQS[1:0]_t_A, DQS[1:0]_c_A	I/O	<b>Data Strobe:</b> DQS_t and DQS_c are bi-directional differential output clock signals used to strobe data during a READ or WRITE. The Data Strobe is generated by the DRAM for a READ and is edge-aligned with Data. The Data Strobe is generated by the Memory Controller for a WRITE and must arrive prior to Data. Each byte of data has a Data Strobe signal pair.
DMI[1:0]_A	I/O	<b>Data Mask Inversion:</b> DMI is a bi-directional signal which is driven HIGH when the data on the data bus is inverted, or driven LOW when the data is in its normal state. Data Inversion can be disabled via a mode register setting. Each byte of data has a DMI signal.
ZQ	Reference	<b>Calibration Reference:</b> Used to calibrate the output drive strength and the termination resistance. There is one ZQ pin per die. The ZQ pin shall be connected to V <sub>DDQ</sub> through a 240Ω ± 1% resistor.
V <sub>DDQ</sub> , V <sub>DD1</sub> , V <sub>DD2</sub>	Supply	<b>Power Supplies:</b> Isolated on the die for improved noise immunity.
V <sub>SS</sub> , V <sub>SSQ</sub>	GND	<b>Ground Reference:</b> Power supply ground reference
RESET_n	Input	<b>RESET:</b> When asserted LOW, the RESET_n signal resets both channels of the die.

**ORDERING INFORMATION – Valid Part Numbers**

**IS 43 LQ 16128 \_ A \_ - 062 B L I**



**TEMPERATURE RANGE**

I = Industrial (-40°C to +95°C)  
A1 = Automotive A1 Grade (-40°C to +95°C)  
A2 = Automotive A2 Grade (-40°C to +105°C)  
A3 = Automotive A3 Grade (-40°C to +125°C)

**PACKAGING CONTENT**

L = RoHS compliant

**Package Type**

B = 200-ball BGA (0.85mm Max. Thickness)  
TB = 200-ball BGA (1.1mm Max. Thickness)

**Speed Grade**

075 = 1333MHz  
062 = 1600MHz

**VDDQ**

Blank = Regular VDDQ  
L = Low VDDQ (LPDDR4X)

**Die Generation**

A = 1<sup>st</sup> Generation

**ECC support**

Blank = No ECC Support  
E = On Chip ECC Support

**Density**

16128 = 128Mb x 16 (2Gb)

**Device Type**

LQ = LPDDR4 DRAM

**Product Family**

43 = DDR DRAM  
46 = Automotive DDR DRAM

**ISSI Prefix**

IS = Integrated Silicon Solution Inc.

**ORDERING INFORMATION, 128Mb x 16 LPDDR4**
**Industrial Range: Tc = -40°C to +95°C**

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS43LQ16128A-062BLI	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS43LQ16128A-062TBLI	200-ball FBGA, 1.1mm max. thickness, Lead-free

**Automotive, A1 Range: Tc = -40°C to +95°C**

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS46LQ16128A-062BLA1	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS46LQ16128A-062TBLA1	200-ball FBGA, 1.1mm max. thickness, Lead-free

**Automotive, A2 Range: Tc = -40°C to +105°C**

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS46LQ16128A-062BLA2	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS46LQ16128A-062TBLA2	200-ball FBGA, 1.1mm max. thickness, Lead-free

**Automotive, A3 Range: Tc = -40°C to +125°C**

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS46LQ16128A-062BLA3	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS46LQ16128A-062TBLA3	200-ball FBGA, 1.1mm max. thickness, Lead-free

**ORDERING INFORMATION, 128Mb x 16 LPDDR4X**

Industrial Range: Tc = -40°C to +95°C

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS43LQ16128AL-062BLI	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS43LQ16128AL-062TBLI	200-ball FBGA, 1.1mm max. thickness, Lead-free

Automotive, A1 Range: Tc = -40°C to +95°C

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS46LQ16128AL-062BLA1	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS46LQ16128AL-062TBLA1	200-ball FBGA, 1.1mm max. thickness, Lead-free

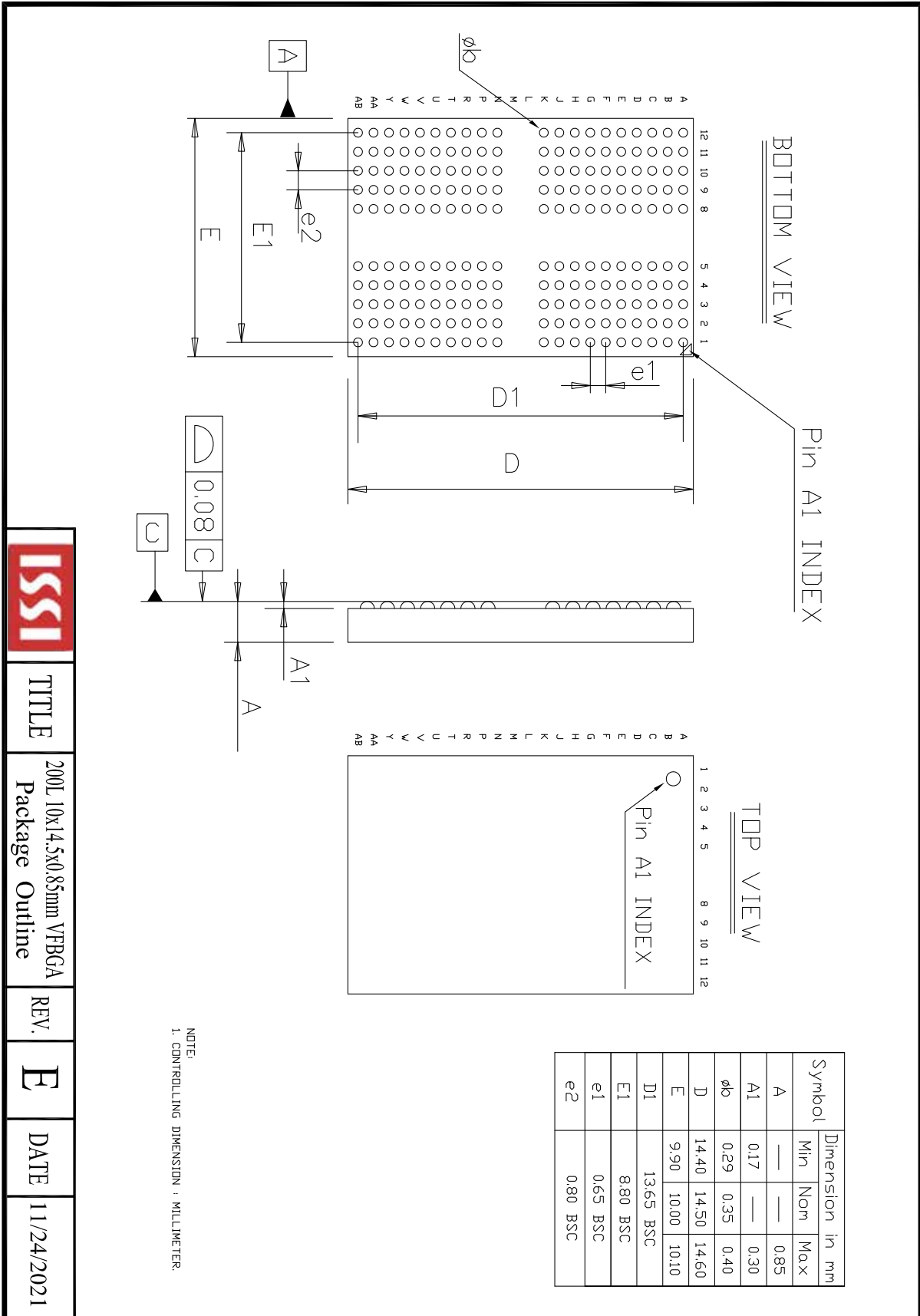
Automotive, A2 Range: Tc = -40°C to +105°C

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS46LQ16128AL-062BLA2	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS46LQ16128AL-062TBLA2	200-ball FBGA, 1.1mm max. thickness, Lead-free

Automotive, A3 Range: Tc = -40°C to +125°C

Clock	Speed Grade	Order Part No.	Package
1600 MHz	-062	IS46LQ16128AL-062BLA3	200-ball FBGA, 0.85mm max. thickness, Lead-free
		IS46LQ16128AL-062TBLA3	200-ball FBGA, 1.1mm max. thickness, Lead-free

PACKAGE INFORMATION: 200-ball FBGA



TITLE  
200L 10x14.5x0.85mm VFPGA  
Package Outline

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DATE

11/24/2021